



#14/Amndt C  
BOX 115  
REPLY UNDER 37 C.F.R. § 1.116  
EXPEDITED PROCEDURE  
EXAMINING GROUP 2828  
PATENT  
0020-4666P  
2/6/03

IN THE U.S. PATENT AND TRADEMARK OFFICE

Applicant: Fumihiro KONUSHI et al. Conf.: 1396  
Application No.: 09/492,803 Group: 2828  
Filed: January 28, 2000 Examiner: Q. Leung  
For: SEMICONDUCTOR LASER DEVICE AND METHOD  
OF MANUFACTURING SAME

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AMENDMENT AFTER FINAL UNDER 37 C.F.R. 1.116

Assistant Commissioner for Patents  
Washington, DC 20231

February 3, 2002

Sir:

In reply to the Office Action dated November 5, 2002, the following amendments and remarks are respectfully submitted in the above-identified application.

IN THE CLAIMS:

Please cancel claim 11 without prejudice or disclaimer of the subject matter contained therein.

Please amend Claim 1 as follows:

1. (Three Times Amended) A semiconductor laser device having a quantum well active layer disposed between a pair of cladding layers, and an optical guide layer disposed between at least one of the cladding layers and the quantum well active layer,

OK for entry

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